# LA0151CS

# Monolithic Linear IC Ambient Light Sensor, Linear Current Output, with 2-Stage Gain Switching, Ultra-small Package

#### Overview

The LA0151CS is a photo IC for ultra-small ambient light sensor. It eLinables to be mounted on a very small limited space such as on the mobile phones which is becoming small and thinner and on other mobile applications.

#### **Functions**

- Linear current output
- Low gain mode function [low gain : -35dB]

#### **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub>		6	V
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-40 to +100	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### Recommended operating conditions and operating voltage range at Ta = 25°C

Parameter		Conditions	Ratings			
	Symbol		min	typ	max	Unit
Recommended supply voltage	VCC		2.2	3.3	5.5	V
SW pin low voltage	VI	Normal gain mode	0		0.4	V
SW pin high voltage	Vh	Low gain mode	2.1			V

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#### Electrical and optical characteristics at Ta = $25^{\circ}$ C, V<sub>CC</sub> = 3.3V

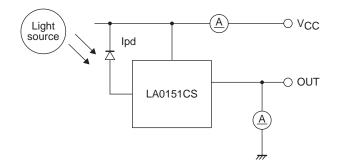
Parameter	Quarteral			Ratings		
	Symbol	Conditions	min	typ	max	Unit
Current dissipation (1) *1, *3	ICC	$Ev = 1000 \text{ lx}, \text{ R}_{L} = 5 \text{k}\Omega, \text{ N} \text{ mode}$	90	150	210	μA
Current dissipation (2) *1, *3	ICC	$Ev = 1000 \text{ lx}, \text{ R}_{L} = 5 \text{k}\Omega, \text{ L} \text{ mode}$	42	70	98	μΑ
Output current (1) *1, *3	I <sub>O</sub> 1	Ev = 100 lx, N mode	6	8	10	μΑ
Output current (2) *1, *3	I <sub>O</sub> 2	Ev = 1000 lx, N mode	60	80	100	μΑ
Output current (3) *1, *3	IO3	Ev = 100 lx, L mode	0.12	0.16	0.2	μΑ
Output current (4) *1, *3	I <sub>O</sub> 4	Ev = 1000 lx, L mode	1.2	1.6	2.0	μΑ
Dark current	lleak	Ev = 0 lx, N mode, L mode			0.1	μΑ
Temperature coefficient *2	Itc	Ev = 100 lx, N mode, L mode,		0.34		%/°C
		Ta = -20 to 60°C				
Rise time (1) *4	Tr1	$Ev = 1000 \text{ lx}, \text{ R}_{L} = 5 \text{k}\Omega, \text{ N} \text{ mode}$		15	40	μS
Rise time (2) *4	Tr2	$Ev = 1000 \text{ lx}, \text{ R}_{L} = 500 \text{k}\Omega, \text{ L} \text{ mode}$		20	50	μS
Fall time (1) *4	Tf1	$Ev = 1000 \text{ lx}, \text{ R}_{L} = 5 \text{k}\Omega, \text{ N mode}$		150	500	μS
Fall time (2) *4	Tf2	Ev = 1000 lx, $R_L$ = 500k $\Omega$ , L mode		150	500	μS
Peak sensitivity wave length *2	λρ			550		nm
Saturation output voltage *5	Vo	Ev = 1000 lx, R <sub>L</sub> = 150kΩ, N mode	3.0	3.2		V

N mode and L mode stand for the normal gain mode and the low gain mode, respectively.

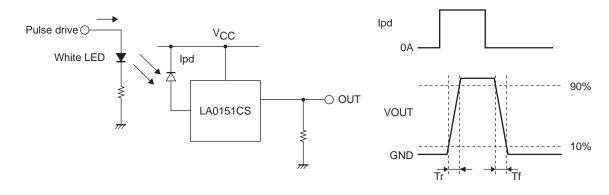
\*1. Measured with the standard light source A. White LED is used instead in the mass production line.

\*2. Design guaranteed item

\*3. Test circuit for measuring current dissipation and output current



\*4. Measuring method of rise time (Tr) and fall time (Tf)

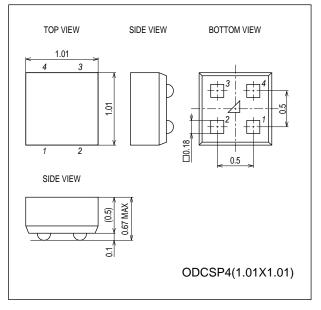


\*5. Reference value : min = 2.6V and typ = 2.8V when  $V_{\mbox{CC}}$  = 2.9V

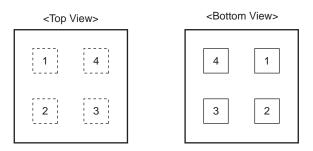
#### Package Dimensions

unit : mm (typ)

3350A



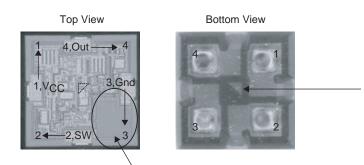
# Pad layout



Pin No.	Pin Name	Function
1	V <sub>CC</sub>	Power supply
2	SW	Switch
3	GND	Ground
4	OUT	Output

Ball pitch : 0.5mm, Ball size : 0.18mm<sup> $\Box$ </sup>

# Pad layout (Photos)

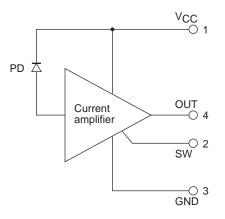


Pin 1 mark It is located at the center of the bottom of the pakage.

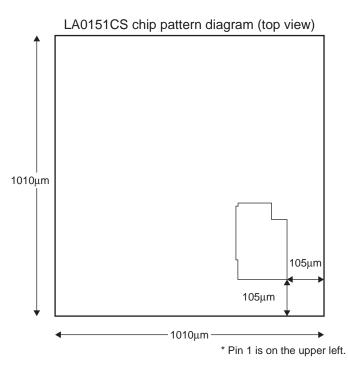
Photo diode. Only this part looks dark on the product.

\* The photo diode is located in pin 3. Be careful not to mistake the pin 1 mark for the photo diode.

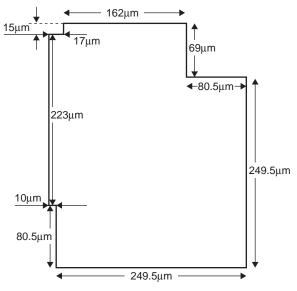
#### Internal block diagram

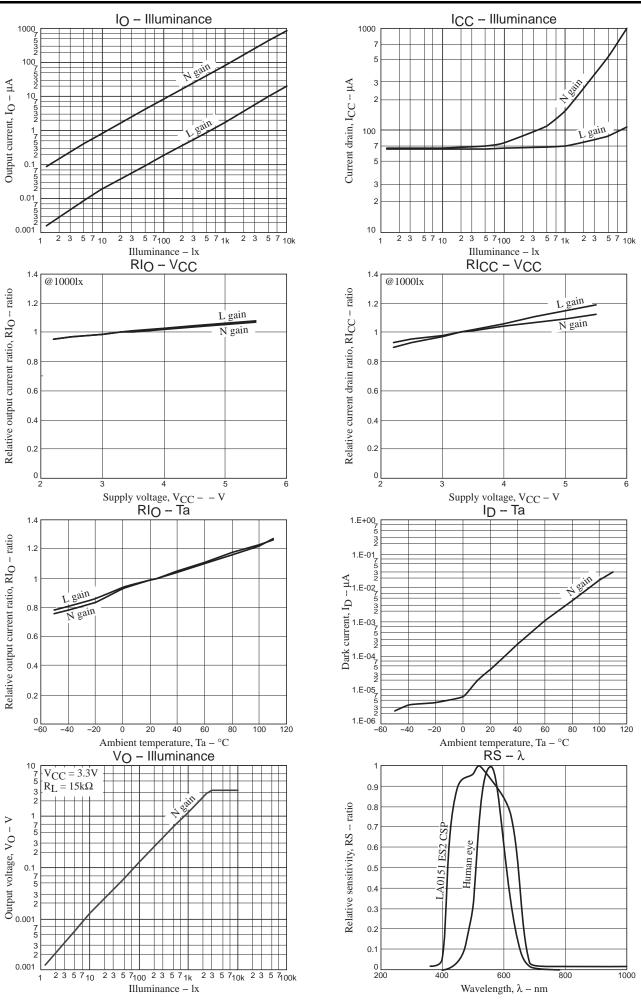


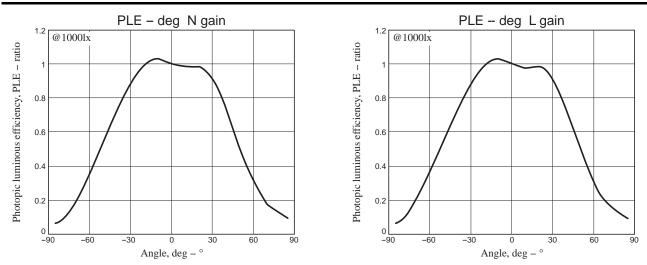
# Chip pattern and photo-receiving pattern diagrams



LA0151CS photo-receiving pattern enlarged diagram (effective area)







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